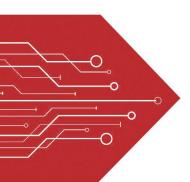
MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data sheet









SOT - 23



- 1. BASE
- 2. EMITTER
- 3. COLLECTOR

FEATURES

• Complementary Type FMMT493

MARKING:593

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-120	V
V _{CEO}	Collector-Emitter Voltage	-100	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current	-1	Α
Pc	Collector Power Dissipation	250	mW
R _{OJA}	Thermal Resistance From Junction To Ambient	500	°C/W
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55∼+150	℃

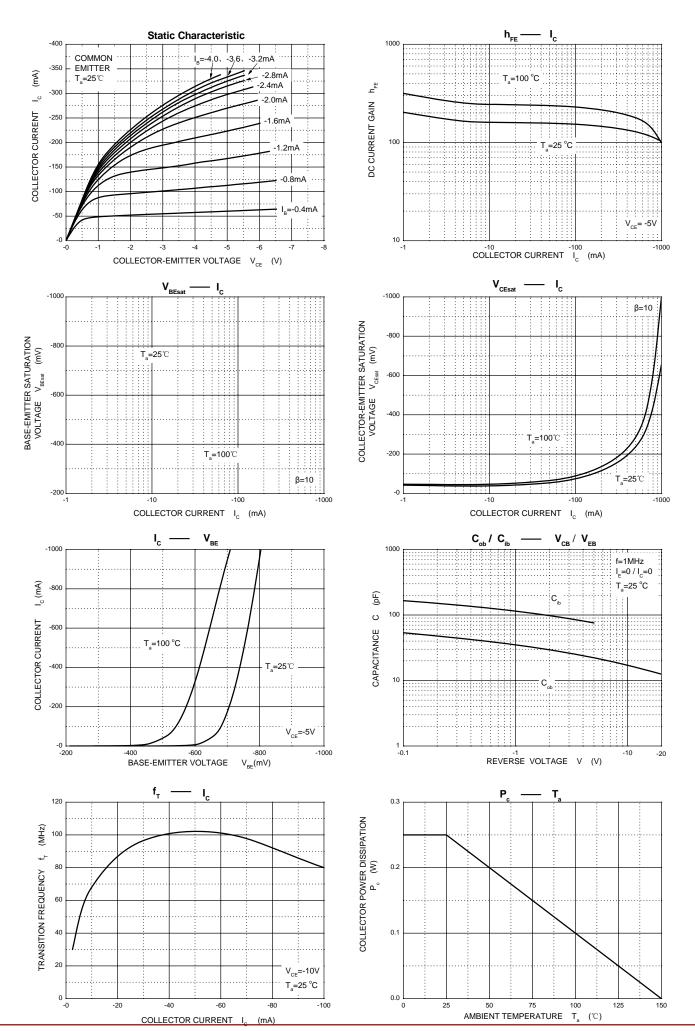
ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-100μA, I _E =0	-120			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-10mA, I _B =0	-100			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-100μA, I _C =0	-5			V
Collector cut-off current	I _{CBO}	V _{CB} =-100V, I _E =0			-0.1	μA
Collector cut-off current	I _{CES}	V _{CES} =-100V, I _E =0			-0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} =-4V, I _C =0			-0.1	μA
	h _{FE(1)} *	V _{CE} =-5V, I _C =-1mA	100			
DC current gain	h _{FE(2)} *	V _{CE} =-5V, I _C =-250mA	100			
DC current gam	h _{FE(3)} *	V _{CE} =-5V, I _C =-0.5A	100		300	
	h _{FE(4)} *	V _{CE} =-5V, I _C =-1A	50			
Collector-emitter saturation voltage	V _{CE(sat)1} *	I _C =-250mA, I _B =-25mA			-0.2	V
Conector-enlitter Saturation Voltage	V _{CE(sat)2} *	I _C =-500mA, I _B =-50mA			-0.3	V
Base-emitter saturation voltage	V _{BE(sat)} *	I _C =-500mA, I _B =-50mA			-1.1	V
Base-emitter voltage	V _{BE} *	V _{CE} =-5V, I _C =-1mA			-1	V
Transition frequency	f⊤	V _{CE} =-10V,I _C =-50mA, f=100MHz	50			MHz
Collector output capacitance	C_{ob}	V _{CB} =-10V, I _E =0, f=1MHz		5		pF

^{*}Pulse test: pulse width ≤300µs, duty cycle≤ 2.0%.

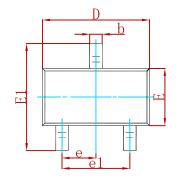
Semiconductor

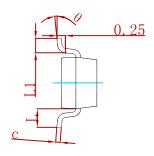


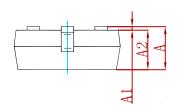




PACKAGE MECHANICAL DATA

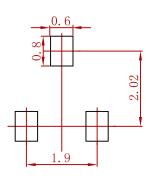






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
Е	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.03	7 TYP	
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

Suggested Pad Layout



- 1.Controlling dimension:in millimeters.2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
FMMT593	SOT-23	3000



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